BLC10G19LS-250WT

Power LDMOS transistor

Rev. 1 — 19 October 2017

AMPLEON

Product data sheet

1. Product profile

1.1 General description

250 W LDMOS power transistor for base station applications at frequencies from 1930 MHz to 1990 MHz.

Table 1. Typical performance

Typical RF performance at T_{case} = 25 °C in a common source class-AB demo application.

Test signal	f	I_{Dq}	V_{DS}	$P_{L(AV)}$	G_p	η_D	ACPR
	(MHz)	(mA)	(V)	(W)	(dB)	(%)	(dBc)
2-carrier W-CDMA	1930 to 1990	1400	28	60	19.3	31	−31 [1]

[1] Test signal: 3GPP test model 1; 64 DPCH; PAR = 8.4 dB at 0.01 % probability on CCDF; carrier spacing 5 MHz.

1.2 Features and benefits

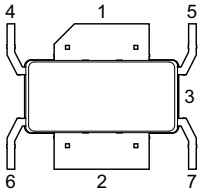
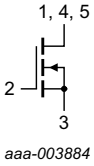
- Excellent ruggedness
- Excellent video bandwidth enabling full band operation
- High efficiency
- Low thermal resistance providing excellent thermal stability
- Designed for low memory effects providing excellent pre-distortability
- Device can operate with the supply current delivered through video leads
- Internally matched for ease of use
- Integrated ESD protection
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

1.3 Applications

- RF power amplifier for W-CDMA base stations and multi carrier applications in the 1930 MHz to 1990 MHz frequency range

2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
1	drain		
2	gate		
3	source [1]		
4	video decoupling		
5	video decoupling		
6	n.c.		
7	n.c.		

[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BLC10G19LS-250WT	-	Air cavity plastic earless flanged package; 6 leads	SOT1271-2

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage		-	65	V
V_{GS}	gate-source voltage		−0.5	+13	V
T_{stg}	storage temperature		−65	+150	°C
T_j	junction temperature	[1]	-	225	°C

[1] Continuous use at maximum temperature will affect the reliability, for details refer to the online MTF calculator.

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Typ	Unit
$R_{th(j-c)}$	thermal resistance from junction to case	T_{case} = 80 °C; P_L = 60 W	0.28	K/W

6. Characteristics

Table 6. DC characteristics

T_j = 25 °C, unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{(BR)DSS}$	drain-source breakdown voltage	V_{GS} = 0 V; I_D = 2.715 mA	65	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	V_{DS} = 10 V; I_D = 272 mA	1.6	2.0	-	V
V_{GSq}	gate-source quiescent voltage	V_{DS} = 28 V; I_D = 1400 mA	1.5	2.0	2.5	V
I_{DSS}	drain leakage current	V_{GS} = 0 V; V_{DS} = 32 V	-	-	1.4	μA
I_{DSX}	drain cut-off current	V_{GS} = $V_{GS(th)}$ + 2.37 V; V_{DS} = 10 V	-	49	-	A
I_{GSS}	gate leakage current	V_{GS} = 9 V; V_{DS} = 0 V	-	-	420	nA
g_{fs}	forward transconductance	V_{DS} = 10 V; I_D = 13.6 A	-	29.5	-	S
$R_{DS(on)}$	drain-source on-state resistance	V_{GS} = $V_{GS(th)}$ + 2.37 V; I_D = 9.5 A	-	0.05	-	Ω

Table 7. RF characteristics

Test signal: 2-carrier W-CDMA; 3GPP test model 1 with 64 DPCH; PAR = 8.4 dB at 0.01 % probability on the CCDF; f_1 = 1932.5 MHz; f_2 = 1937.5 MHz; f_3 = 1982.5 MHz; f_4 = 1987.5 MHz; RF performance at V_{DS} = 28 V; I_{Dq} = 1400 mA; T_{case} = 25 °C; unless otherwise specified; in a water cooled class-AB test circuit.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
G_p	power gain	$P_{L(AV)}$ = 60 W	18.2	19.3	-	dB
η_D	drain efficiency	$P_{L(AV)}$ = 60 W	27	31	-	%
RL_{in}	input return loss	$P_{L(AV)}$ = 60 W	-	−14	−10	dB
$ACPR_{5M}$	adjacent channel power ratio (5 MHz)	$P_{L(AV)}$ = 60 W	-	−31	−27	dBc

7. Test information

7.1 Ruggedness in class-AB operation

The BLC10G19LS-250WT is capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions: V_{DS} = 28 V; I_{Dq} = 1400 mA; 2-carrier W-CDMA signal; P_L = 120 W average; f_c = 1930 MHz; 5 MHz spacing; 46 % clipping.

7.2 Impedance information

Table 8. Typical impedance

Measured load-pull data; I_{Dq} = 1400 mA; V_{DS} = 28 V; pulsed CW (t_p = 100 μs; δ = 10 %).

f	Z_S [1]	Z_L [1]	P_L [2]	η_D [2]	G_p [2]
(MHz)	(Ω)	(Ω)	(W)	(%)	(dB)
Maximum power load					
1930	1.1 – j4.6	1.1 – j2.8	426.9	65.1	17.1
1960	1.4 – j4.5	1.1 – j2.8	423.3	66.7	17.5
1990	1.9 – j5.3	0.9 – j2.8	424.3	62.8	17.1
Maximum drain efficiency load					
1930	1.1 – j4.6	1.5 – j2.4	361.0	70.5	18.5
1960	1.4 – j4.5	1.6 – j2.3	347.5	71.2	19.0
1990	1.9 – j5.3	1.5 – j2.1	321.4	71.7	19.5

[1] Z_S and Z_L defined in Figure 1.

[2] at 3 dB gain compression.

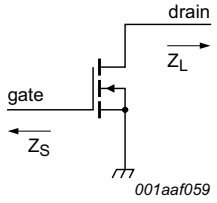
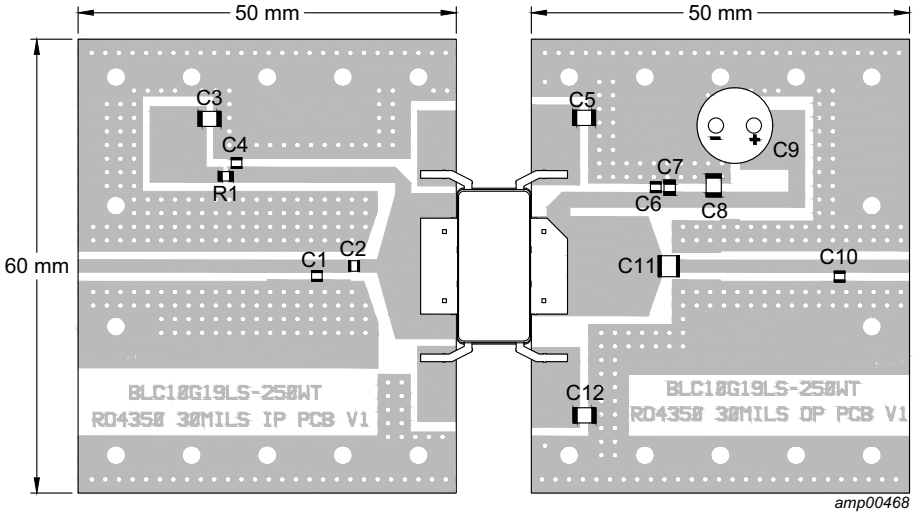


Fig 1. Definition of transistor impedance

7.3 Test circuit



Printed-Circuit Board (PCB): Rogers RO4350B with a thickness of 0.76 mm.

See Table 9 for a list of components.

Fig 2. Component layout for test circuit

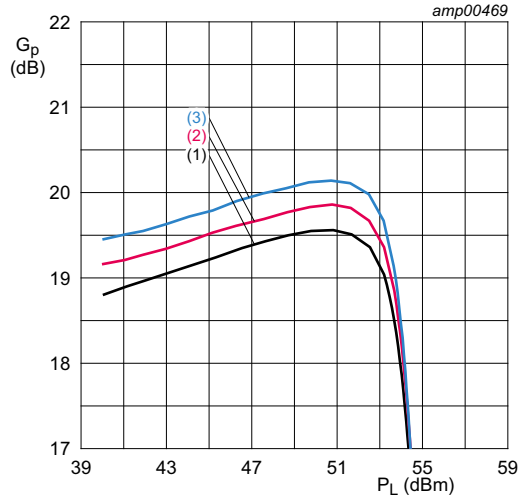
Table 9. List of components

See Figure 2 for component layout.

Component	Description	Value	Remarks
C1	multilayer ceramic chip capacitor	1.6 pF	ATC 100A
C2	multilayer ceramic chip capacitor	3.3 pF	ATC 100A
C3, C5, C8, C12	multilayer ceramic chip capacitor	4.7 μF, 100 V	Murata
C4, C6	multilayer ceramic chip capacitor	22 pF	ATC 100A
C7	multilayer ceramic chip capacitor	100 nF	Murata
C9	electrolytic capacitor	> 470 μF, 63 V	low ESR
C10	multilayer ceramic chip capacitor	0.5 pF	ATC 100A
C11	multilayer ceramic chip capacitor	1.4 pF	ATC 100A
R1	resistor	4.7 Ω, 1 % tolerance	SMD 0805

7.4 Graphical data

7.4.1 Pulsed CW



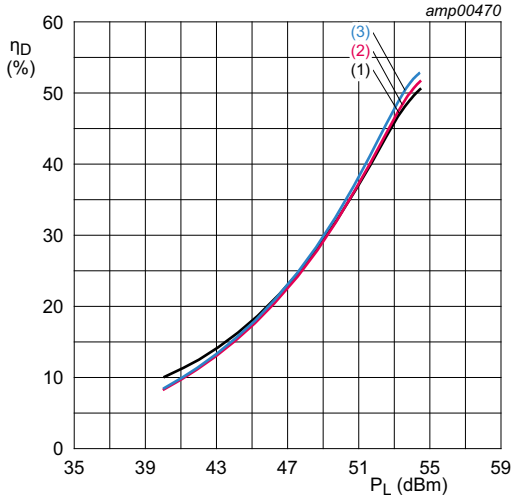
V_{DS} = 28 V; I_{Dq} = 1400 mA; t_p = 100 μs; δ = 10 %.

(1) f = 1930 MHz

(2) f = 1960 MHz

(3) f = 1990 MHz

Fig 3. Power gain as a function of output power; typical values



V_{DS} = 28 V; I_{Dq} = 1400 mA; t_p = 100 μs; δ = 10 %.

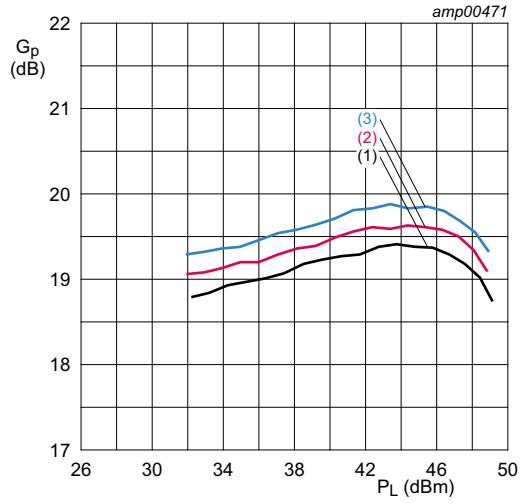
(1) f = 1930 MHz

(2) f = 1960 MHz

(3) f = 1990 MHz

Fig 4. Drain efficiency as a function of output power; typical values

7.4.2 IS-95



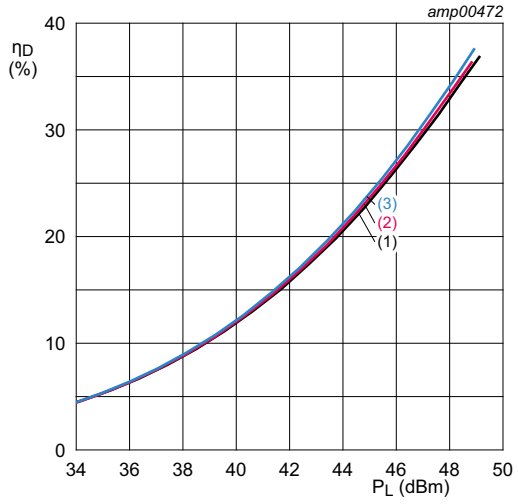
V_{DS} = 28 V; I_{Dq} = 1400 mA.

(1) f = 1935 MHz

(2) f = 1960 MHz

(3) f = 1985 MHz

Fig 5. Power gain as a function of output power; typical values



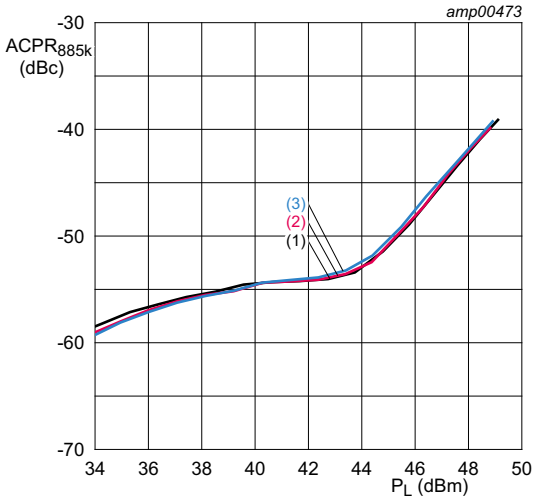
V_{DS} = 28 V; I_{Dq} = 1400 mA.

(1) f = 1935 MHz

(2) f = 1960 MHz

(3) f = 1985 MHz

Fig 6. Drain efficiency as a function of output power; typical values



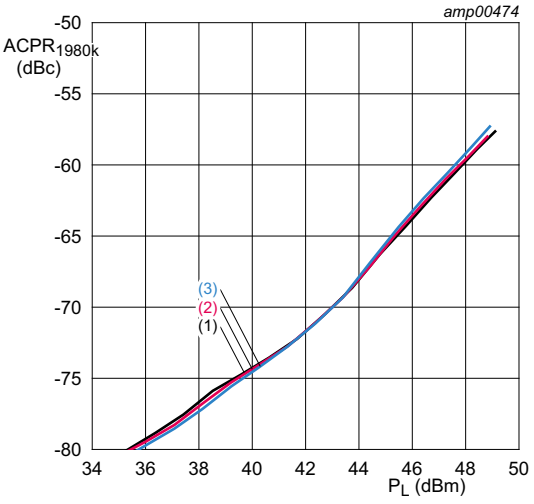
V_{DS} = 28 V; I_{Dq} = 1400 mA.

(1) f = 1935 MHz

(2) f = 1960 MHz

(3) f = 1985 MHz

Fig 7. Adjacent channel power ratio (885 kHz) as a function of output power; typical values



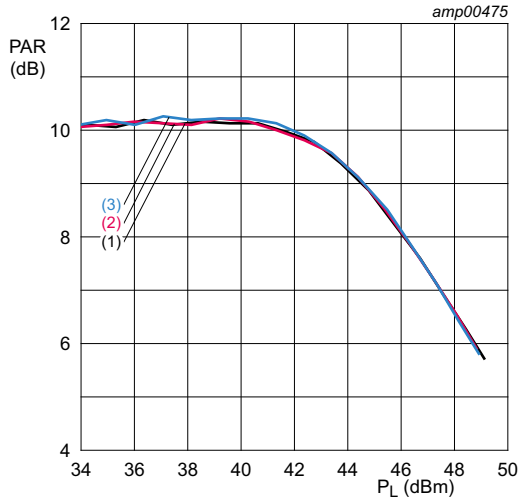
V_{DS} = 28 V; I_{Dq} = 1400 mA.

(1) f = 1935 MHz

(2) f = 1960 MHz

(3) f = 1985 MHz

Fig 8. Adjacent channel power ratio (1980 kHz) as a function of output power; typical values



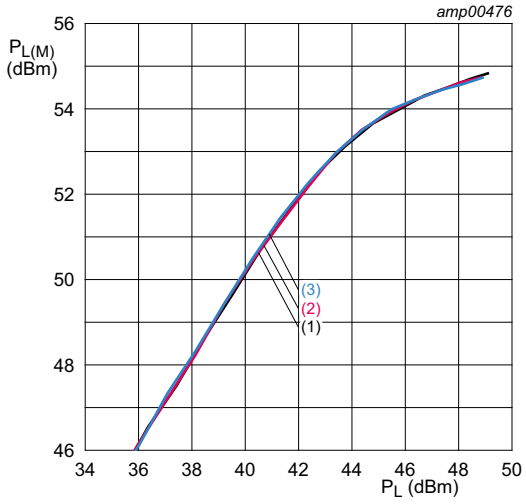
V_{DS} = 28 V; I_{Dq} = 1400 mA.

(1) f = 1935 MHz

(2) f = 1960 MHz

(3) f = 1985 MHz

Fig 9. Peak-to-average ratio as a function of output power; typical values



V_{DS} = 28 V; I_{Dq} = 1400 mA.

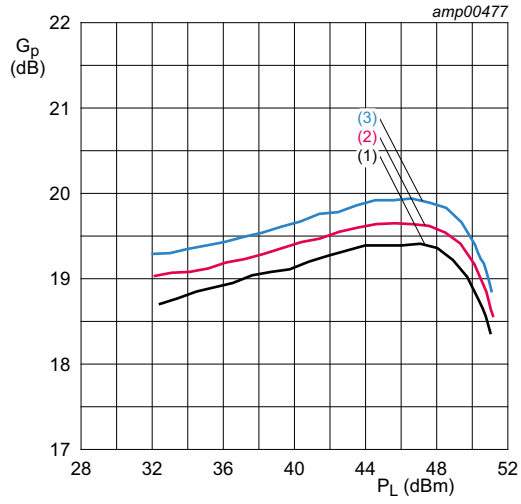
(1) f = 1935 MHz

(2) f = 1960 MHz

(3) f = 1985 MHz

Fig 10. Peak output power as a function of output power; typical values

7.4.3 1-Carrier W-CDMA



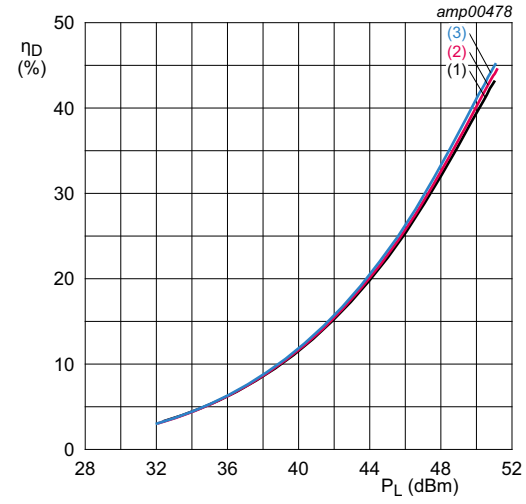
V_{DS} = 28 V; I_{Dq} = 1400 mA.

(1) f = 1932.5 MHz

(2) f = 1960 MHz

(3) f = 1987.5 MHz

Fig 11. Power gain as a function of output power; typical values



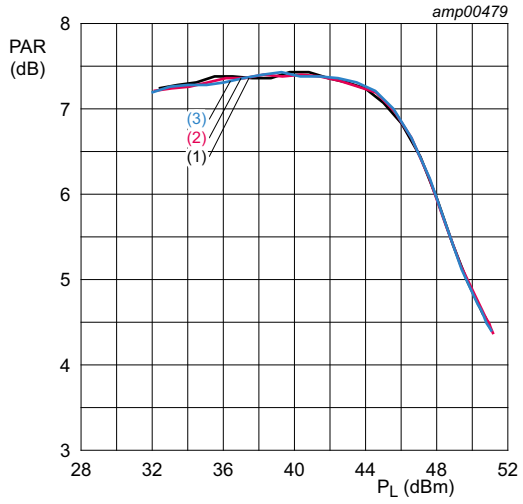
V_{DS} = 28 V; I_{Dq} = 1400 mA.

(1) f = 1932.5 MHz

(2) f = 1960 MHz

(3) f = 1987.5 MHz

Fig 12. Drain efficiency as a function of output power; typical values



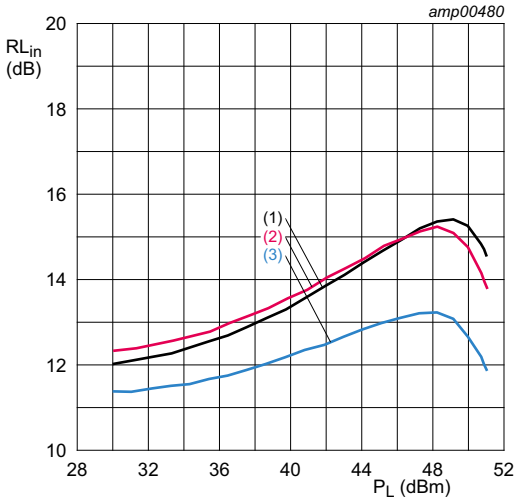
V_{DS} = 28 V; I_{Dq} = 1400 mA.

(1) f = 1932.5 MHz

(2) f = 1960 MHz

(3) f = 1987.5 MHz

Fig 13. Peak-to-average ratio as a function of output power; typical values



V_{DS} = 28 V; I_{Dq} = 1400 mA.

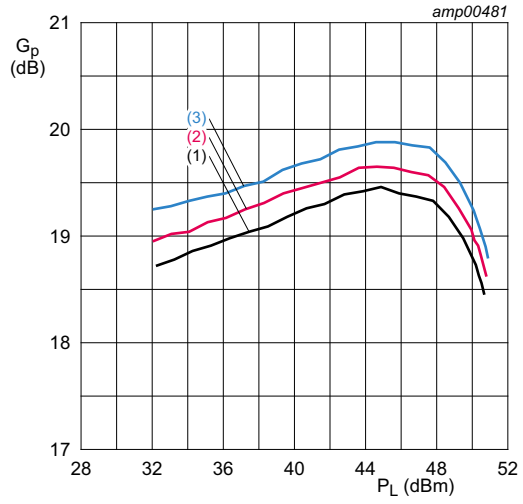
(1) f = 1932.5 MHz

(2) f = 1960 MHz

(3) f = 1987.5 MHz

Fig 14. Input return loss as a function of output power; typical values

7.4.4 2-Carrier W-CDMA



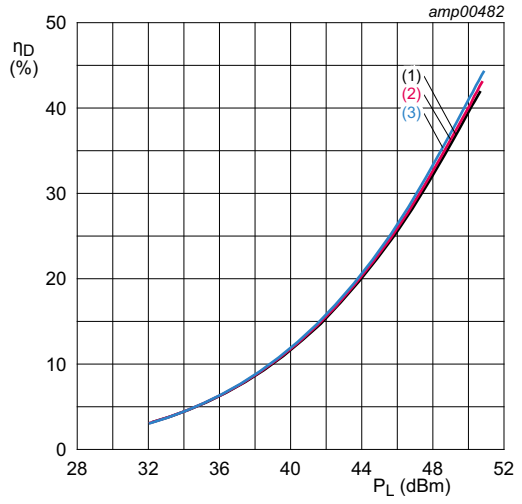
V_{DS} = 28 V; I_{Dq} = 1400 mA.

(1) f = 1935 MHz

(2) f = 1960 MHz

(3) f = 1985 MHz

Fig 15. Power gain as a function of output power; typical values



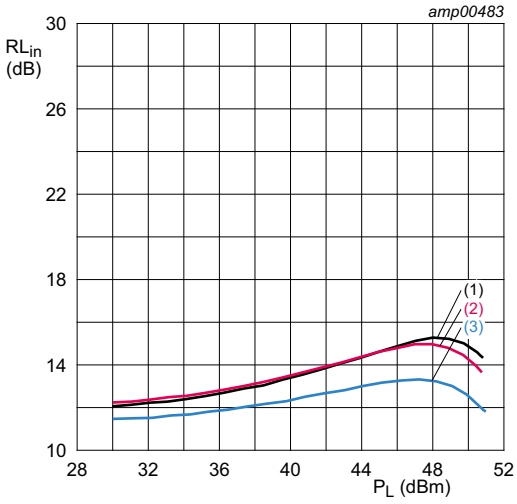
V_{DS} = 28 V; I_{Dq} = 1400 mA.

(1) f = 1935 MHz

(2) f = 1960 MHz

(3) f = 1985 MHz

Fig 16. Drain efficiency as a function of output power; typical values



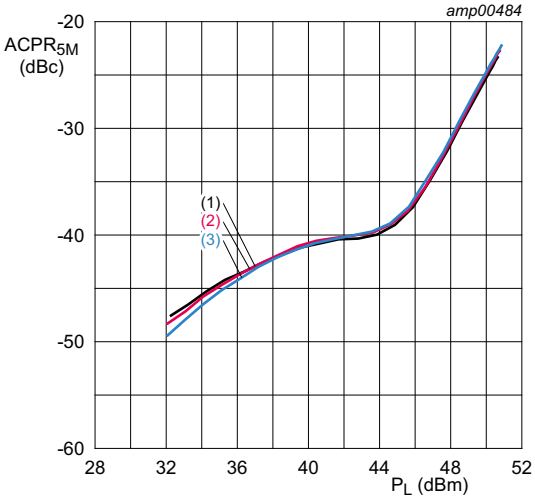
V_{DS} = 28 V; I_{Dq} = 1400 mA.

(1) f = 1935 MHz

(2) f = 1960 MHz

(3) f = 1985 MHz

Fig 17. Input return loss as a function of output power; typical values



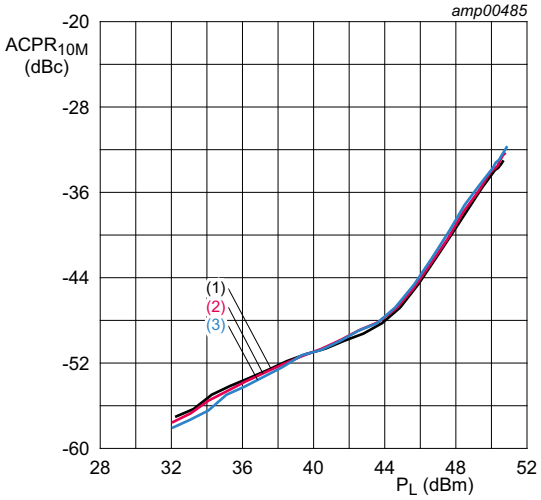
V_{DS} = 28 V; I_{Dq} = 1400 mA.

(1) f = 1935 MHz

(2) f = 1960 MHz

(3) f = 1985 MHz

Fig 18. Adjacent channel power ratio (5 MHz) as a function of output power; typical values



V_{DS} = 28 V; I_{Dq} = 1400 mA.

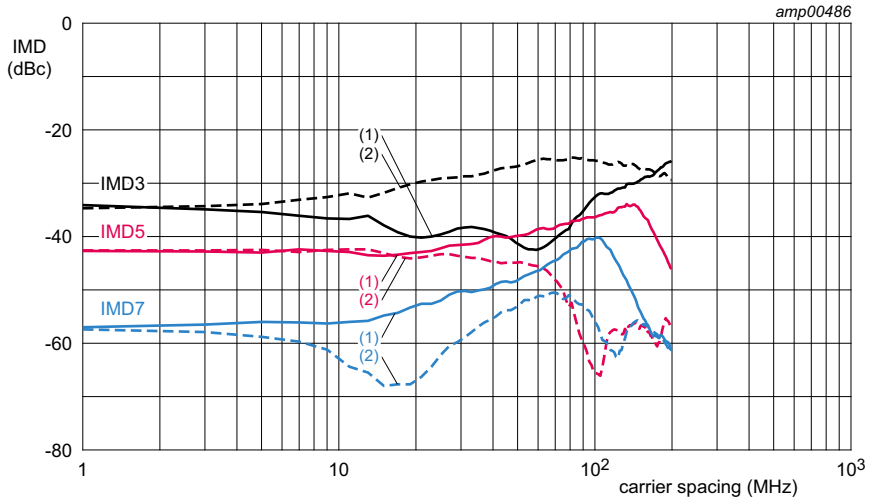
(1) f = 1935 MHz

(2) f = 1960 MHz

(3) f = 1985 MHz

Fig 19. Adjacent channel power ratio (10 MHz) as a function of output power; typical values

7.4.5 2-Tone VBW



V_{DS} = 28 V; I_{Dq} = 1400 mA.

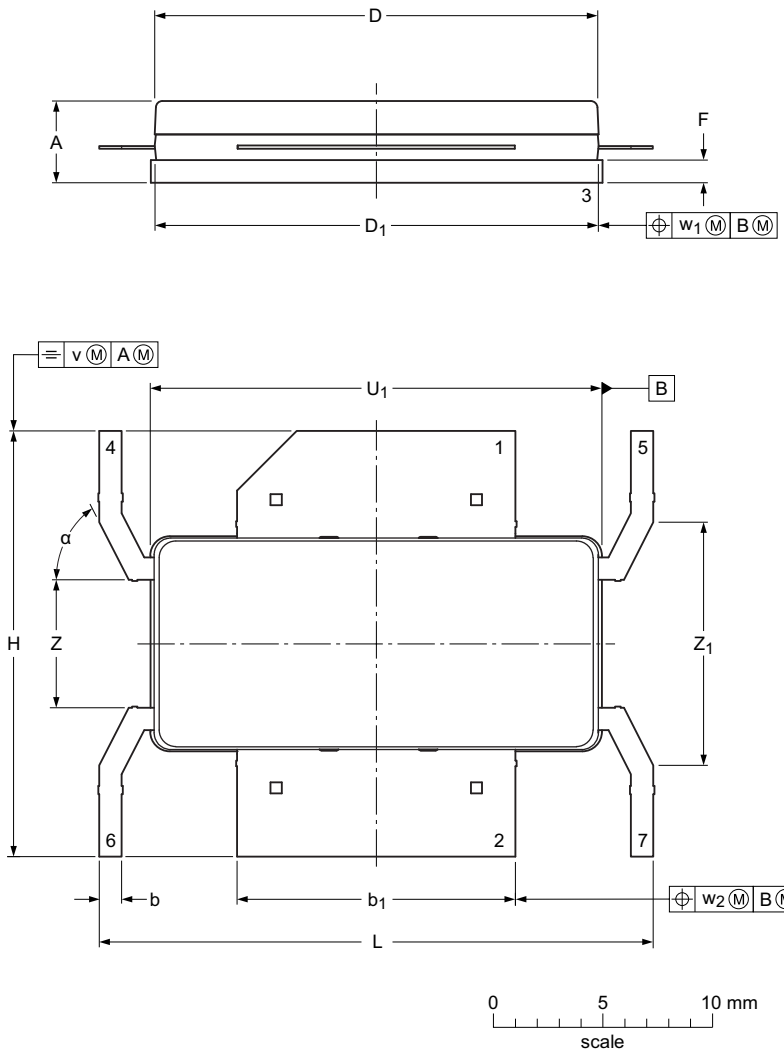
(1) low

(2) high

Fig 20. VBW capability in class-AB test circuit

8. Package outline

Air cavity plastic earless flanged package; 6 leads **SOT1271-2**



Z_1	α
11.19	65°
10.99	61°

Dimensions

Unit		A	b	b_1	c	D	D_1	E	E_1	F	H	L	$Q^{(1)}$	U_1	U_2	v	w_1	w_2	y	Z
mm	max	4.01	1.14	12.80	0.18	20.42	20.37	9.80	9.75	1.14	19.53	25.40	1.68	20.70	9.91	0.50	0.50	0.50	0.10	5.94
	nom																			
	min	3.40	0.89	12.60	0.13	20.12	20.17	9.50	9.55	0.94	19.33	25.20	1.45	20.50	9.70					5.74

Note:
1. Dimension Q is measured at 0.1 mm away from the flange.
2. Ringframe and/or ringframe glue shall not overhang at the side of the flange.

sot1271-2_po

Outline version	References				European projection	Issue date
	IEC	JEDEC	JEITA			
SOT1271-2						17-04-13

Fig 21. Package outline SOT1271-2

9. Handling information

CAUTION

This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the *ANSI/ESD S20.20*, *IEC/ST 61340-5*, *JESD625-A* or equivalent standards.

Table 10. ESD sensitivity

ESD model	Class
Charged Device Model (CDM); According to ANSI/ESDA/JEDEC standard JS-002	C3 [1]
Human Body Model (HBM); According to ANSI/ESDA/JEDEC standard JS-001	2 [2]

[1] CDM classification C3 is granted to any part that passes after exposure to an ESD pulse of ≥ 1000 V.

[2] HBM classification 2 is granted to any part that passes after exposure to an ESD pulse of 2000 V, but fails after exposure to an ESD pulse of 4000 V.

10. Abbreviations

Table 11. Abbreviations

Acronym	Description
3GPP	3rd Generation Partnership Project
CCDF	Complementary Cumulative Distribution Function
CW	Continuous Wave
DPCH	Dedicated Physical CHannel
ESD	ElectroStatic Discharge
IS-95	Interim Standard 95
LDMOS	Laterally Diffused Metal Oxide Semiconductor
MTF	Median Time to Failure
PAR	Peak-to-Average Ratio
SMD	Surface Mounted Device
VSWR	Voltage Standing Wave Ratio
W-CDMA	Wideband Code Division Multiple Access

11. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BLC10G19LS-250WT v.1	20171019	Product data sheet	-	-

12. Legal information

12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.ampleon.com.

12.2 Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. Ampleon does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local Ampleon sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

Product specification — The information and data provided in a Product data sheet shall define the specification of the product as agreed between Ampleon and its customer, unless Ampleon and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the Ampleon product is deemed to offer functions and qualities beyond those described in the Product data sheet.

12.3 Disclaimers

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, Ampleon does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. Ampleon takes no responsibility for the content in this document if provided by an information source outside of Ampleon.

In no event shall Ampleon be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, Ampleon's aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the *Terms and conditions of commercial sale* of Ampleon.

Right to make changes — Ampleon reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — Ampleon products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of an Ampleon product can reasonably be expected to result in personal injury, death or severe property or environmental damage. Ampleon and its suppliers accept no liability for inclusion and/or use of Ampleon products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. Ampleon makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using Ampleon products, and Ampleon accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the Ampleon product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

Ampleon does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using Ampleon products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). Ampleon does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — Ampleon products are sold subject to the general terms and conditions of commercial sale, as published at http://www.ampleon.com/terms, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. Ampleon hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of Ampleon products by customer.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

Export control — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

Non-automotive qualified products — Unless this data sheet expressly states that this specific Ampleon product is automotive qualified, the product is not suitable for automotive use. It is neither qualified nor tested in accordance with automotive testing or application requirements. Ampleon accepts no liability for inclusion and/or use of non-automotive qualified products in automotive equipment or applications.

In the event that customer uses the product for design-in and use in automotive applications to automotive specifications and standards, customer (a) shall use the product without Ampleon's warranty of the product for such automotive applications, use and specifications, and (b) whenever customer uses the product for automotive applications beyond Ampleon's specifications such use shall be solely at customer's own risk, and (c) customer fully indemnifies Ampleon for any liability, damages or failed product claims resulting from customer design and use of the product for automotive applications beyond Ampleon's standard warranty and Ampleon's product specifications.

Translations — A non-English (translated) version of a document is for reference only. The English version shall prevail in case of any discrepancy between the translated and English versions.

12.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

Any reference or use of any 'NXP' trademark in this document or in or on the surface of Ampleon products does not result in any claim, liability or entitlement vis-à-vis the owner of this trademark. Ampleon is no longer part of the NXP group of companies and any reference to or use of the 'NXP' trademarks will be replaced by reference to or use of Ampleon's own trademarks.

13. Contact information

For more information, please visit: **http://www.ampleon.com**

For sales office addresses, please visit: **http://www.ampleon.com/sales**

14. Contents

For more information, please visit: http://www.ampleon.com
For sales office addresses, please visit: http://www.ampleon.com/sales

Date of release: 19 October 2017
Document identifier: BLC10G19LS-250WT